# Cryo STEM of Low Melting Point Metals Enabled by Cryo FIB and EXLO

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DECTRIS

## ARINA with NOVENA Fast 4D STEM



DECTRIS NOVENA and CoM analysis of a magnetic sample.

Sample courtey: Dr. Christian Liebscher, May-Hanck-Institut für Eisenforschung GmbH.

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### Microscopy AND Microanalysis

## **Cryo STEM of Low Melting Point Metals Enabled by Cryo FIB** and EXLO

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Cryogenic techniques have significantly expanded the materials accessible for study in electron microscopy. The development of the cryo-focused ion beam (cryo-FIB) has enabled site-specific analysis in unique systems such as biological specimens, liquid-solid interfaces, and environmentally sensitive materials [1, 2]. Furthermore, this tool facilitates the implementation of specimen preparation techniques for high-resolution characterization with cryogenic scanning/transmission electron microscopy (cryo-S/TEM). Cryo-FIB lift-out specimen preparation is a powerful technique for researching these systems. However, successful in situ specimen manipulation is often challenging due to issues with specimen attachment, thermal stability, and the structural integrity of the specimen [3]. The cryogenic ex situ lift out (cryo EXLO) technique has recently been developed to address these challenges and has successfully been applied to both soft matter organic polymers and biological vitreous materials [4]. In this work, we demonstrate, through a combination of cryo-FIB thinning and EXLO manipulation, the preparation of high-quality, electron-transparent specimens of low-melting-point indium metal (mp=156.6°C).

Recent studies have revealed that the issues associated with room temperature milling conditions in indium metal, leading to void formation, cannot be solely attributed to reactivity with the Ga<sup>+</sup> ion beam, as voids form irrespective of the FIB ion used (e.g., Ga+ or Xe+) [5]. Rather than the ion source, this milling issue is associated with fundamental ion-solid interactions, where low melting point materials typically exhibit higher FIB milling sputter yields. Previous work has also shown that the sputter yield of a material increases as a function of temperature once it reaches ~70% of its absolute melting point [6]. We also have evidence of increased FIB milling sputter yields as a function of temperature. With Xe FIB milling, the sputter yield increases to ~ 20% when milled at a stage temperature of 25°C compared to 55°C.

For this reason, to properly address proper milling conditions in indium metal, cryogenic temperatures are necessary. With the indium metal cooled to -175°C, we can achieve thin, electron-transparent specimens without noticeable void formation (Figure 1a). The stage is then warmed back to room temperature and specimen manipulation to a TEM grid is accomplished with EXLO manipulation. This grid is transferred to a S/TEM, where it is cooled back to liquid nitrogen temperatures for cryo-STEM imaging (Figure 1b). In STEM, we achieved atomic resolution of the indium crystal structure, indicating the specimen was sufficiently thinned and free from significant surface contamination with final 5 kV milling (Figure 1c). This work presents an effective method for the preparation and high-resolution study of challenging, low-melting-point metals through a combination of cryo-FIB and EXLO techniques [7].

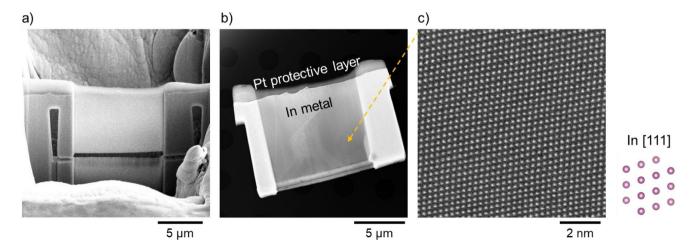


Fig. 1. a) SEM image of cryo-FIB thinned indium metal specimen. b) Cryo-STEM HAADF overview showing successful transfer to TEM. c) Atomic resolution of indium [111] lattice demonstrates quality of FIB specimen.

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